



## RF AMPLIFIER PENTODE

**5847**  
**404 A**

Intended for use up to ultrahigh frequencies. It features low noise, high transconductance, and low inter-electrode capacitances.

The frame grid, described in Section A, with a lateral wire diameter of only .0065 mm provides high broadband qualities and freedom from microphonics.

### COLD CAPACITANCES (without external shield)

Grid No 1 to Plate . . . . .	max. .05	$\mu\mu F$
Input . . . . .	7.0	$\mu\mu F$
Output . . . . .	2.5	$\mu\mu F$

### RANGE VALUES FOR CAPACITANCES (external shield connected to cathode)

	MIN	MAX	
Grid No 1 to Plate . . . . .	.04	$\mu\mu F$	
Input . . . . .	6.6	7.8	$\mu\mu F$
Output . . . . .	2.9	3.4	$\mu\mu F$

### ABSOLUTE MAXIMUM RATINGS

Plate Voltage . . . . .	200	volts
Grid No 2 Voltage . . . . .	165	volts
Grid No 1 Voltage, positive value . . . . .	+ 0	volt
Grid No 1 Voltage, negative value . . . . .	- 25	volts
Cathode Current . . . . .	40	ma
Plate Dissipation . . . . .	3.3	watts
Grid No 2 Dissipation (see Section A) . . . . .	.85	watt
Heater — Cathode Voltage . . . . .	55	volts
Bulb Temperature, at hottest point . . . . .	150	°C
Grid No 1 Circuit Resistance		
with fixed bias . . . . .	.05	Mohm
with cathode bias . . . . .	.1	Mohm

### MECHANICAL DATA

Base: Small Button Noval 9-pin,  
RETMA E9-1

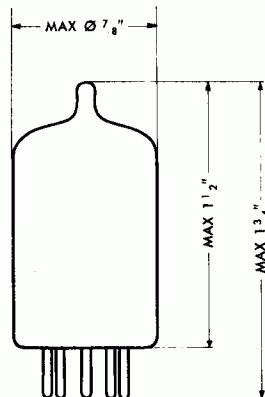
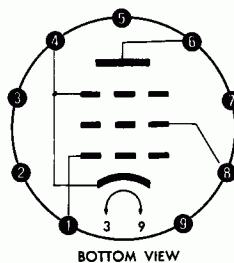
Bulb: EIA T 6½

Mounting Position: Any

#### PIN NO CONNECTED TO

1. Grid No 1
2. No Connection
3. Heater, Upper Int.  
Shield\*
4. Cathode, Grid No 3,  
Lower Int. Shield
5. No Connection
6. Plate
7. No Connection
8. Grid No 2
9. Heater

\*The internal shield connected  
to Pin No 3 should be grounded.



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### TYPICAL OPERATION. CLASS A<sub>1</sub>

Heater Voltage . . . . .	6.3	6.3	volts
Heater Current . . . . .	.3	.3	amp
Plate Supply Voltage . . . . .	150	160	volts
Grid No 2 Supply Voltage . . . . .	150	160	volts
Grid No 1 Supply Voltage . . . . .	+ 8.5		volts
Cathode Bias Resistor . . . . .	110	600	ohms
Plate Current . . . . .	13.5	13.5	ma
Grid No 2 Current . . . . .	4.0	4.0	ma
Transconductance . . . . .	13,000	13,000	$\mu$ hos
Plate Resistance . . . . .	.2	.2	megohm
Grid No 1 Voltage for Plate Current = 10 $\mu$ a . . . . .	— 4.5	— 4.5	volts
Equivalent Noise Resistance . . . . .	500	500	ohms
Transit Time Loading at 100 Mc . . . . .	100	100	$\mu$ hos
Input Conductance at 100 Mc . . . . .	2000	2000	$\mu$ hos

### FIGURE OF MERIT

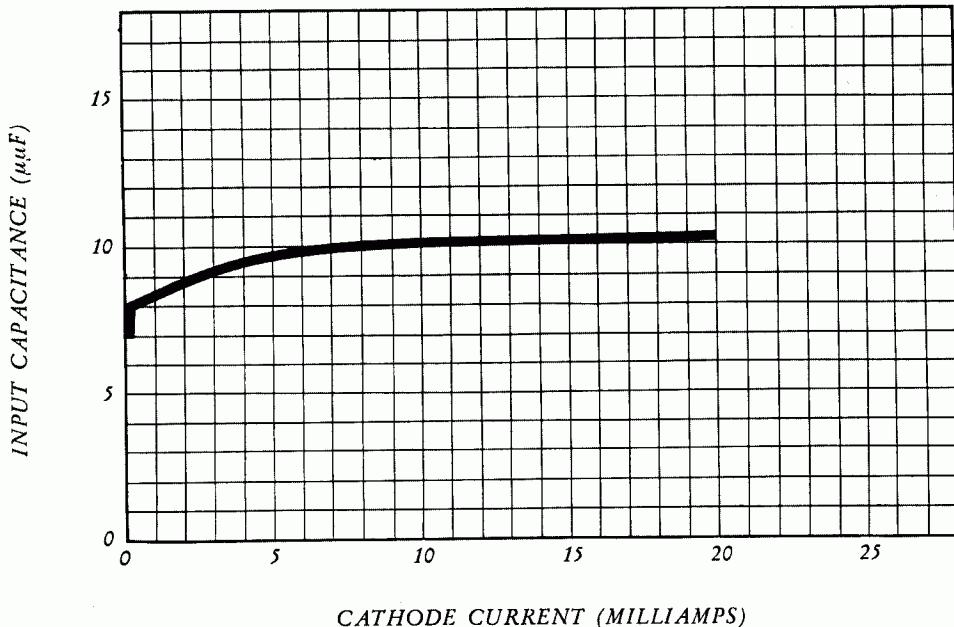
		Tube Cold	Typical operation*
At LF without external shield	$\frac{g_m}{C_{in} + C_{out}}$	1.37	.73
At IF without external shield	$\frac{g_m}{\sqrt{C_{in} \cdot C_{out}}}$	3.1	1.7

\* The following additions have been made for tube sockets and wiring capacitances to get total circuit capacitances under typical operating conditions:

At LF — 5  $\mu$ uF. At IF — 3  $\mu$ uF for input circuit and 2  $\mu$ uF for output circuit.

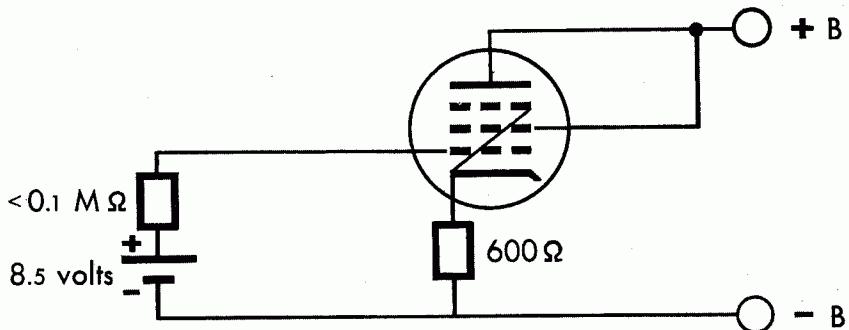
### OPERATION RANGE VALUES

	MIN	AVE	MAX	
Heater Voltage . . . . .	6.3			volts
Plate Supply Voltage . . . . .	150			volts
Grid No 2 Supply Voltage . . . . .	150			volts
Cathode Bias Resistor . . . . .	110			ohms
Heater Current . . . . .	280	300	320	ma
Plate Current . . . . .	9.0	13.5	18.0	ma
Grid No 2 Current . . . . .		4.0	6.0	ma
Transconductance . . . . .	10,000	13,000	16,000	$\mu$ hos
Transconductance, End of Life Point . . . . .	8500			$\mu$ hos
I <sub>hk</sub> at E <sub>hk</sub> = ± 100 volts . . . . .			20	$\mu$ a
Grid No 1 Current . . . . .			— .2	$\mu$ a
Cutoff Plate Current at E <sub>c1</sub> = — 10 volts . . . . .			50	$\mu$ a
Vibration Output . . . . .	5			mv
Measured at 2.5 g and 25 cps. E <sub>f</sub> = 6.3 v, E <sub>bb</sub> = 150 v, E <sub>cc2</sub> = 150 v, R <sub>k</sub> = 110 ohms, C <sub>k</sub> = 2000 $\mu$ F, r <sub>p</sub> = 2000 ohms.				

**SPECIAL DATA**

**CAPACITANCES IN OPERATION:**

Space-charge effects in electron current flow cause an increase in tube capacitances. Input capacitance as a function of cathode current is shown above.

For best value of figure of merit external shield should be excluded.


**BIAS CONSIDERATIONS:**

The operating characteristics of high transconductance tubes are sensitive to variations in manufacture. Because of this the use of a 600 ohm cathode resistance, in conjunction with a DC control grid return to a + 8.5 volt supply, is recommended.

To prevent burning out grid wires by removal of plate voltage when the + 8.5 volt bias is still applied, a limiting resistor of 10,000 ohms in series with the bias supply is suggested. Where the use of such a resistor is not practical, care should be taken to see that the grid bias is not applied before the plate and grid No 2 voltages.

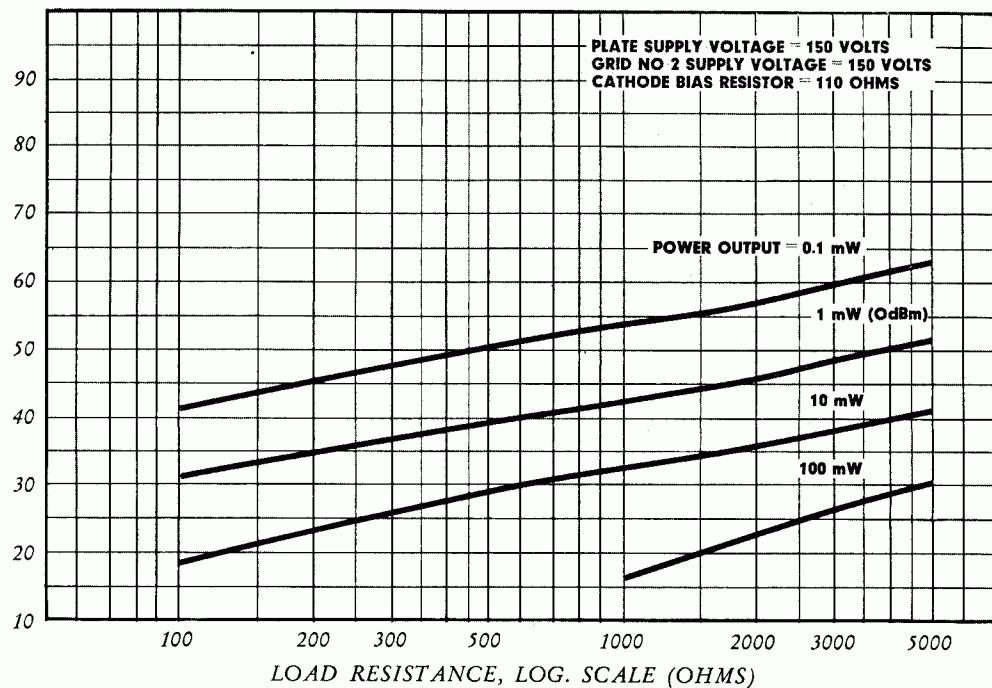
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*404 A*

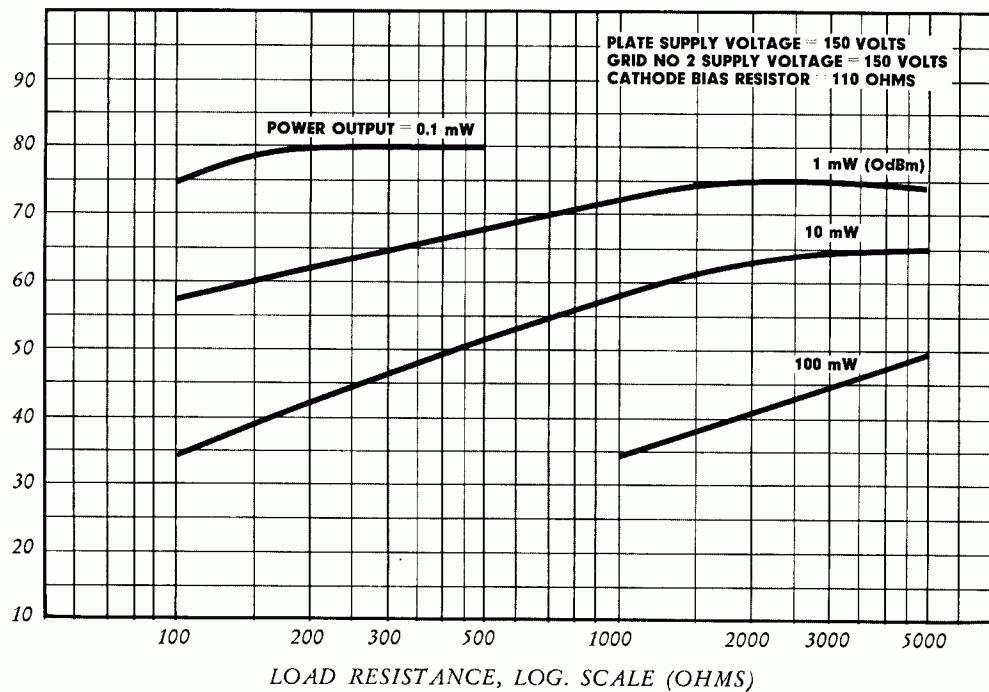
RF AMPLIFIER PENTODE

Ericsson  
GM

VOLTAGE RATIO F/2F (DECIBELS)



VOLTAGE RATIO F/3F (DECIBELS)



#### HARMONIC DISTORTION:

The voltage ratio between fundamental frequency (F), second harmonic (2F) and third harmonic (3F) as a function of the load resistance at different power outputs under typical operating conditions is shown.



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### AVERAGE CHARACTERISTICS

